Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 1.125 inches **Overall Diameter:** 1.000 inches **Mounting Facility Quantity:** 1 Internal Configuration: Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.0 forward voltage, peak and 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes forward current, total rms peak and 150.00 milliamperes forward current, total rms preset **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0